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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC240AP,TC74HC240AF,TC74HC240AFW TC74HC241AP,TC74HC241AF TC74HC244AP,TC74HC244AF,TC74HC244AFW

Octal Bus Buffer

TC74HC240AP/AF/AFW Inverted, 3-State

Outputs

TC74HC241AP/AF Non-Inverted,

3-State Outputs

TC74HC244AP/AF/AFW Non-Inverted,

3-State Outputs

The TC74HC240A, 241A and 244A are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC240A is an inverting 3-state buffer having two active-low output enables. The TC74HC241A and TC74HC244A are non-inverting 3-state buffers that differ only in that the 241A has one active-high and one active-low output enable, and the 244A has two active-low output enables.

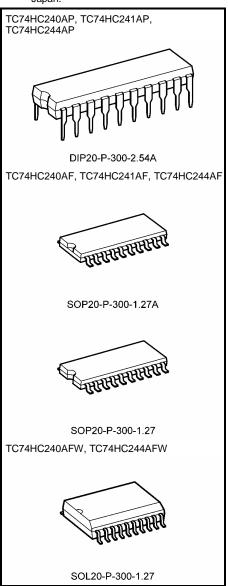
These devices are designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 10 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 6 mA (min)
- Balanced propagation delays: t_pLH ≃ t_pHL
- Wide operating voltage range: VCC (opr) = 2~6 V
- Pin and function compatible with 74LS240/241/244

Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

 DIP20-P-300-2.54A
 : 1.30 g (typ.)

 SOP20-P-300-1.27A
 : 0.22 g (typ.)

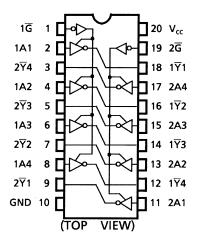
 SOP20-P-300-1.27
 : 0.22 g (typ.)

 SOL20-P-300-1.27
 : 0.46 g (typ.)

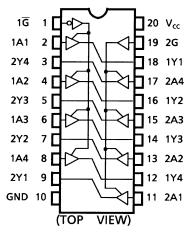
TOSHIBA

Pin Assignment

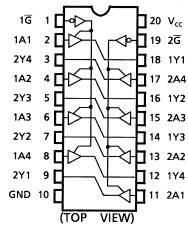
TC74HC240A



TC74HC241A

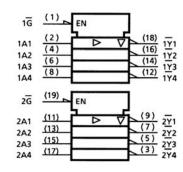


TC74HC244A

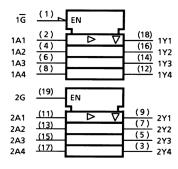


IEC Logic Symbol

TC74HC240A

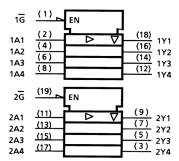


TC74HC241A



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TC74HC244A



Truth Table

	Inputs	Outputs			
G	G [∆]	An	Yn	\overline{Y}_n $\Delta\Delta$	
L	Н	L	L	Н	
L	Н	Н	Н	L	
Н	L	Х	Z	Z	

- Δ: For TC74HC241A only
- $\Delta\Delta$: For TC74HC240A only
- X: Don't care
- Z: High impedance



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	٧
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±35	mA
DC V _{CC} /ground current	I _{CC}	±75	mA
Power dissipation	P _D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Ch are stariation	Comme la cal	Test Condition V _{CC} (V)		Ta = 25°C			Ta = -40~85°C		Llmit	
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
				6.0	4.20	_	_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_	_	1.35	_	1.35	V
					_	_	1.80		1.80	
				2.0	1.9	2.0	_	1.9	_	
	Vон	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0		5.9	_	٧
			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80		5.63	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			$I_{OL} = 6 \text{ mA}$	4.5	_	0.17	0.26		0.33	
			$I_{OL} = 7.8 \text{ mA}$	6.0	_	0.18	0.26		0.33	
3-state output off-state current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	_	±0.5	_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0			±0.1		±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		6.0	_	_	4.0	_	40.0	μА



AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
	t _{TLH}			2.0	_	25	60	_	75	
Output transition time	tTHL	_	50	4.5	_	7	12	_	15	ns
	'I II L			6.0	_	6	10	_	13	
				2.0	_	36	90	_	115	
			50	4.5	_	12	18	_	23	
Propagation delay	t _{pLH}			6.0	_	10	15	_	20	ns
time	tpHL	_		2.0	_	51	130	_	165	115
			150	4.5	_	17	26	_	33	
				6.0	_	14	22	_	28	
	^t pZL ^t pZH	$R_L = 1 \text{ k}\Omega$	50	2.0	_	48	125	_	155	
				4.5	_	16	25	_	31	
Outrot analys times				6.0	_	14	21	_	26	ns
Output enable time			150	2.0	_	63	165	_	205	115
				4.5	_	21	33	_	41	
				6.0	_	18	28	_	35	
				2.0		32	125	_	155	
Output disable time	t _{pLZ}	$R_L = 1 \text{ k}\Omega$	50	4.5	_	15	25	_	31	ns
	t _{pHZ}			6.0	_	14	21	_	26	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF	
Output capacitance	C _{OUT}	_	_		_	10	_	_	_	pF
Power dissipation	C _{PD}	TC74HC240A			_	31	_	_	_	_
capacitance	(Note)	TC74HC241A/244A			_	33	_	_	_	pF

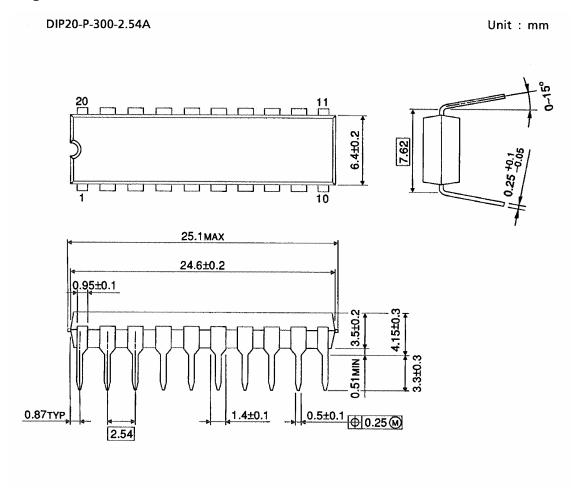
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

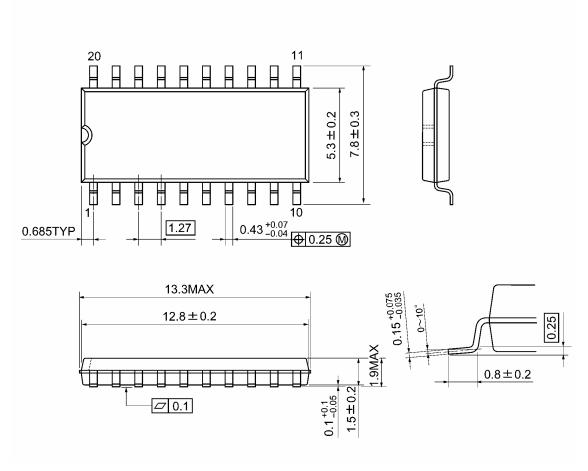
Package Dimensions



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm

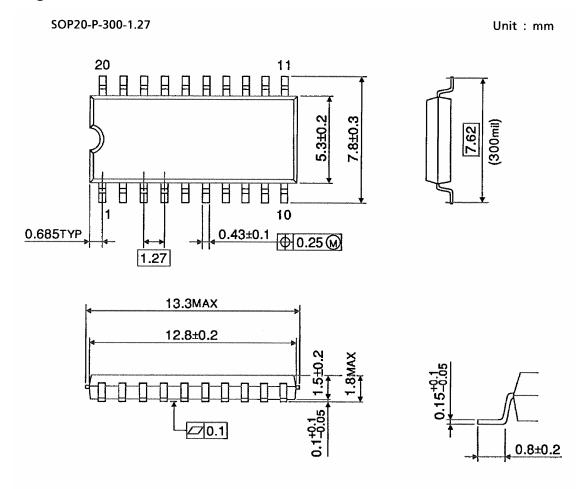


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Weight: 0.22 g (typ.)



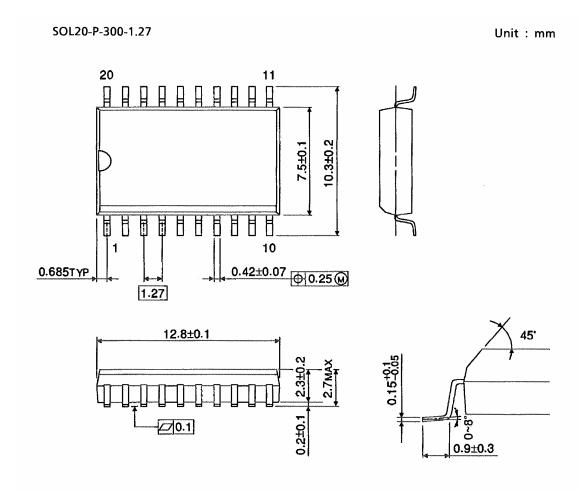
Package Dimensions



Weight: 0.22 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)



Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A

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060116EBA

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